

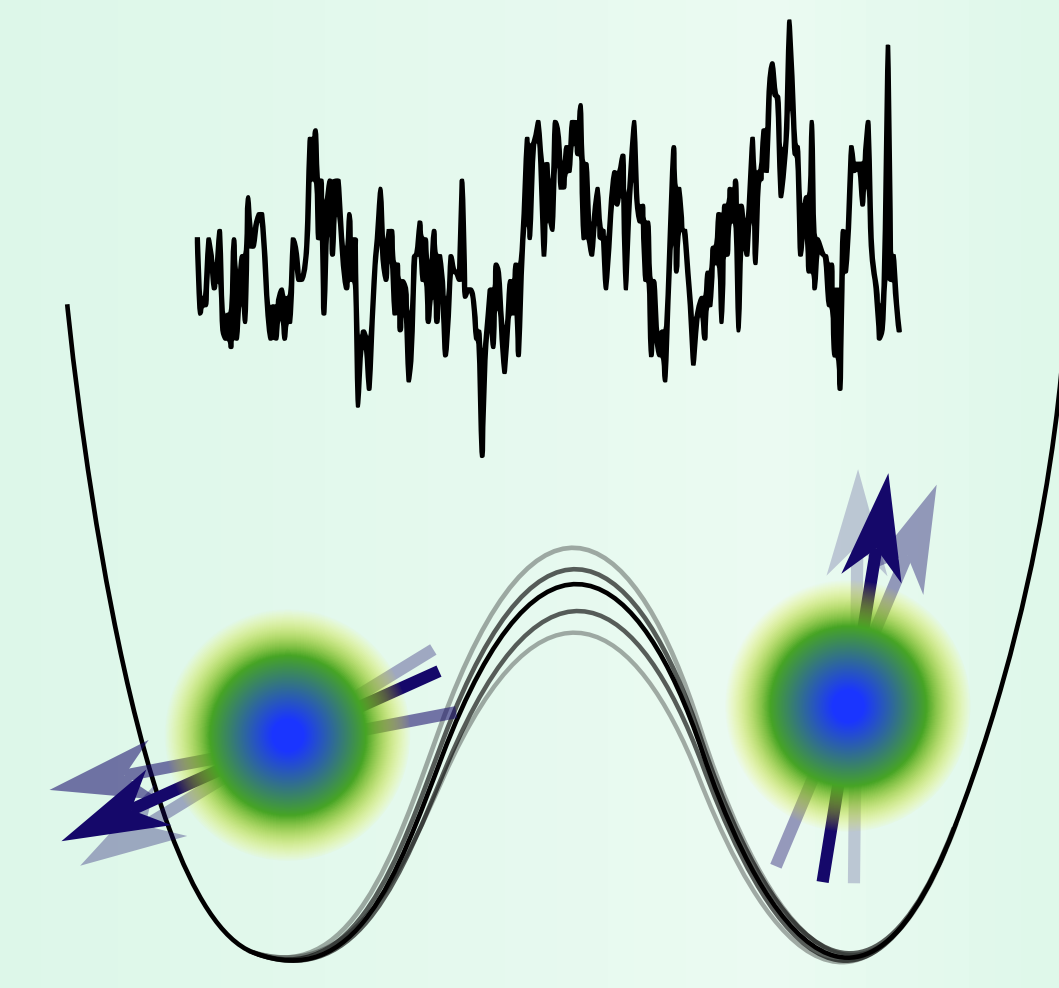
1/f^α-charge-noise-robust voltage control of semiconductor quantum dot spin qubits using fractional calculus

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Long, low-amplitude, and broad exchange pulses, shaped according to the beta distribution function $B(1-\alpha/2, 1-\alpha/2)$, realize the SWAP^k gates least sensitive to stationary 1/f^α charge noise

→ strong exchange interaction may not be necessary for the optimal performance of spin qubit processors

→ this could ease fabrication requirements



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Motivation

Semiconductor quantum dot spin qubits:

✓ Precise voltage control of localized few-electron spin-orbital states

✗ Performance significantly hindered by low-frequency 1/f^α charge noise with 0 < α < 2

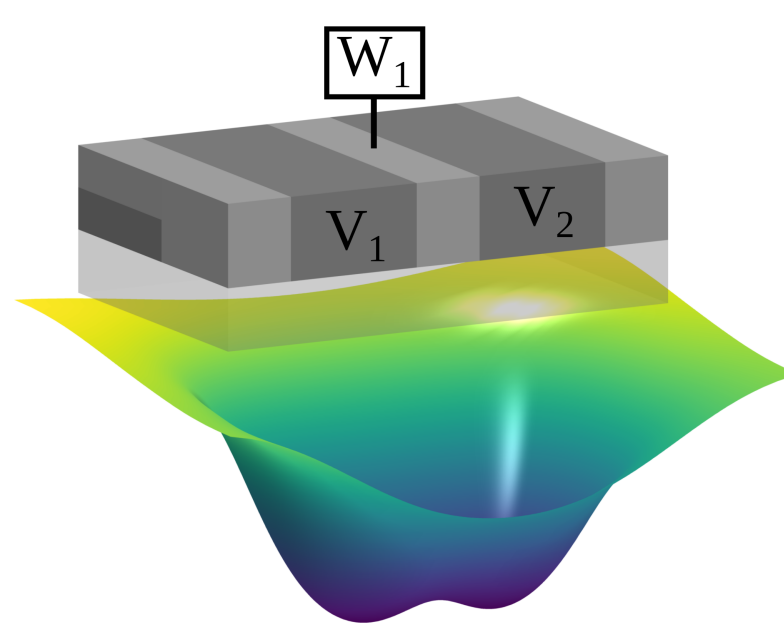


Image: Zach D. Merino

Goal

Develop a new method based on of fractional calculus [1] to design quantum gates least sensitive to 1/f^α noise

Control problem

System

2 silicon quantum dot spin qubits with exchange interaction: $H(t) = \frac{J(t)}{4} \sigma_1 \cdot \sigma_2$

♦ charge noise is the dominant decoherence mechanism

Control

Nonlinear control of exchange with voltage (tunneling electrode / bias): $J(V) \approx J(V_0) \exp[\varkappa(V - V_0)]$

⇒ Exponential amplification of noise $\tilde{v}(t)$ in voltage controls & environment: $J(V + \tilde{v}) = J(V) \exp(\varkappa \tilde{v})$

Quantum gate

2-qubit SWAP^k: $J(t) = \pi k \hbar S(t)/T$ for some normalized shape function $S(t)$:

$$\langle S(t) \rangle = \int_0^1 S(\tau) d\tau = 1, \quad \tau = t/T$$

Performance metric

Unitary infidelity: $\mathcal{F} = 1 - \frac{1}{4} |\text{tr} U^\dagger[V] U[V + \tilde{v}]|$

Average infidelity of a SWAP^k operation:

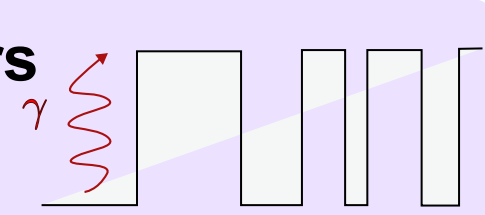
$$\langle \mathcal{F} \rangle \approx \frac{3\pi^2}{32} k^2 \varkappa^2 \int_0^T dt_1 \int_0^T dt_2 S(t_1) S(t_2) R(t_1, t_2),$$

is determined by noise autocorrelation: $R(t_1, t_2) = \langle \tilde{v}(t_1) \tilde{v}(t_2) \rangle$

1/f^α noise models

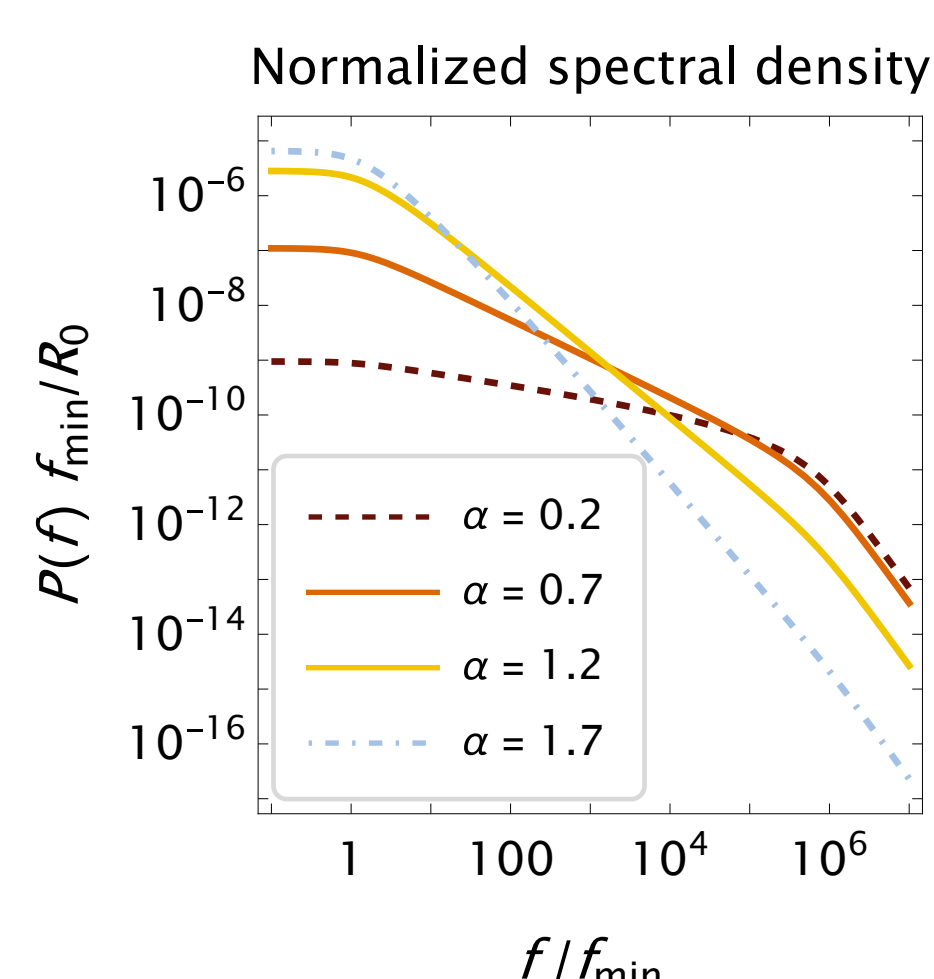
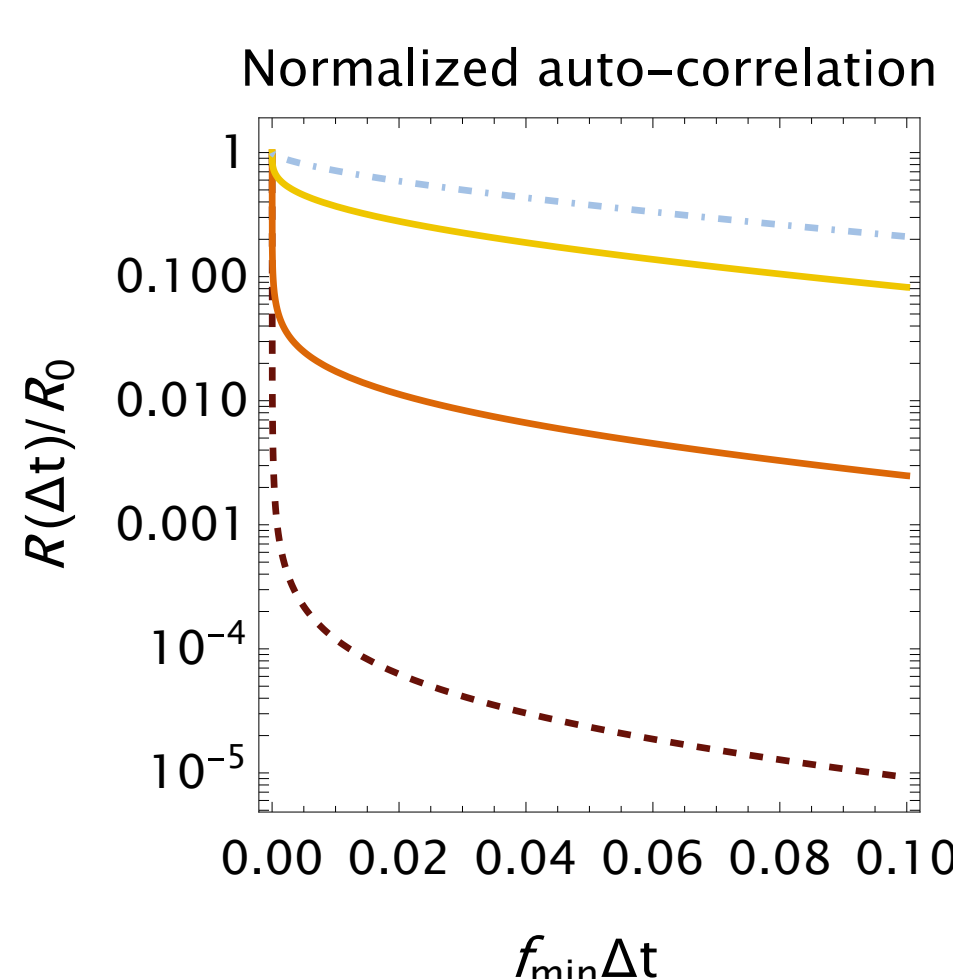
Stationary

Ensemble of two-level fluctuators (TLFs): distributed charge traps



Power-law distribution of fluctuator energies per switching rate γ gives spectrum $\propto 1/f^\alpha$ in the bulk, with autocorrelation

$$R(t_1, t_2) \propto \int_{\min}^{1-\alpha} E_\alpha(2\pi f_{\min}|t_1 - t_2|) - \int_{\max}^{1-\alpha} E_\alpha(2\pi f_{\max}|t_1 - t_2|)$$



Nonstationary

Fractional Brownian motion (fBm): fractional charge transport due to disorder (high charge trap density)

$$R_{\text{fBm}}(\tau_1, \tau_2) \propto \tau_1^{\alpha-1} + \tau_2^{\alpha-1} - |\tau_1 - \tau_2|^{\alpha-1} \quad (1 < \alpha < 2)$$

Methods

1

Fractional calculus

Generalization of integration/differentiation to fractional orders

Motivation: 1/f^α spectral behavior is intermediate between white noise $w(t)$ and Brownian motion $B(t)$: $B(t) = \int_0^t w(s) ds$

Riemann-Liouville fractional integrals:

$$({}_a I_b^\beta \varphi)(x) = \frac{1}{\Gamma(\beta)} \int_a^x (x-s)^{\beta-1} \varphi(s) ds, \quad ({}_b^R I_a^\beta \varphi)(x) = \frac{1}{\Gamma(\beta)} \int_x^b (s-x)^{\beta-1} \varphi(s) ds$$

Riemann-Liouville fractional derivatives are inverse operators:

$${}_a D_b^\beta \varphi = (d/dx)^{\beta+1} {}_a I_b^{1-\beta} \varphi, \quad D_b^\beta \varphi = (-d/dx)^{\beta+1} I_b^{1-\beta} \varphi$$

Left- and right-sided operators are conjugate w.r.t. inner product:

$$\langle \varphi, {}_a I_b^\beta \psi \rangle = \langle I_b^\beta \varphi, \psi \rangle, \quad ({}_a I_b^\beta)^* = I_b^\beta$$

2

Variational minimization

Lagrangian: average infidelity + normalization constraint on exchange pulse shape

$$\Lambda[S] = \langle S, \hat{R}S \rangle - \lambda(1, S) \rightarrow \min_{S(t)}$$

Operator form of autocorrelation determines the existence and functional form of the minimizer!

Optimal shape: derivation for 0 < α < 1

For short SWAP^k pulses compared to the timescale of the experiment $\theta = 2\pi f_{\min} T \sim T/T_{\text{exp}} \ll 1$:

$$R(\tau_1, \tau_2) \propto \frac{\theta^{\alpha-1} \Gamma(2-\alpha)}{|\tau_1 - \tau_2|^{1-\alpha}} - 1, \quad \tau_{1,2} \in [0, 1]$$

$$\text{From [2], } |\tau_1 - \tau_2|^{\alpha-1} = \frac{\pi \int_0^1 ds K(\tau_1, s) K(\tau_2, s) ds}{\Gamma(1-\alpha) \sin \frac{\pi\alpha}{2}} \leftrightarrow \frac{\pi}{\Gamma(1-\alpha) \sin \frac{\pi\alpha}{2}} \hat{K} \hat{K}^* \\ K(\tau, s) = \frac{\tau^{\alpha/2}}{\Gamma(\alpha/2)} (\tau-s)^{\alpha/2-1} s^{-\alpha/2} \mathbb{I}_{[0, \tau]}(s), \quad \hat{K} = \tau^{\alpha/2} \int_0^1 I^{\alpha/2} \tau^{-\alpha/2}$$

This yields a quadratic Lagrangian for $M = \hat{K}^* S$:

$$\Lambda[M] \propto \left[(M, M) - \frac{\theta^{1-\alpha} \sin \frac{\pi\alpha}{2}}{\pi(1-\alpha)} \right] - \lambda (\hat{K}^{-1} M, M)$$

$\delta\Lambda = 0$ yields: $M_{\text{opt}}(\tau) \propto \tau^{\alpha/2} {}_0 D^{\alpha/2} (\tau^{-\alpha/2}) \propto \tau^{-\alpha/2}$

Optimal exchange pulse shape follows from

$S = \tau^{-\alpha/2} D_1^{\alpha/2} \tau^{\alpha/2} M$ and the normalization $(1, S) = 1$:

Optimal exchange pulse shape

Stationary ensemble of TLFs

Non-stationary fBm

$$S_{\text{opt}}(\tau) = \frac{\tau^{-\alpha/2} (1-\tau)^{-\alpha/2}}{B(1-\frac{\alpha}{2}, 1-\frac{\alpha}{2})}$$

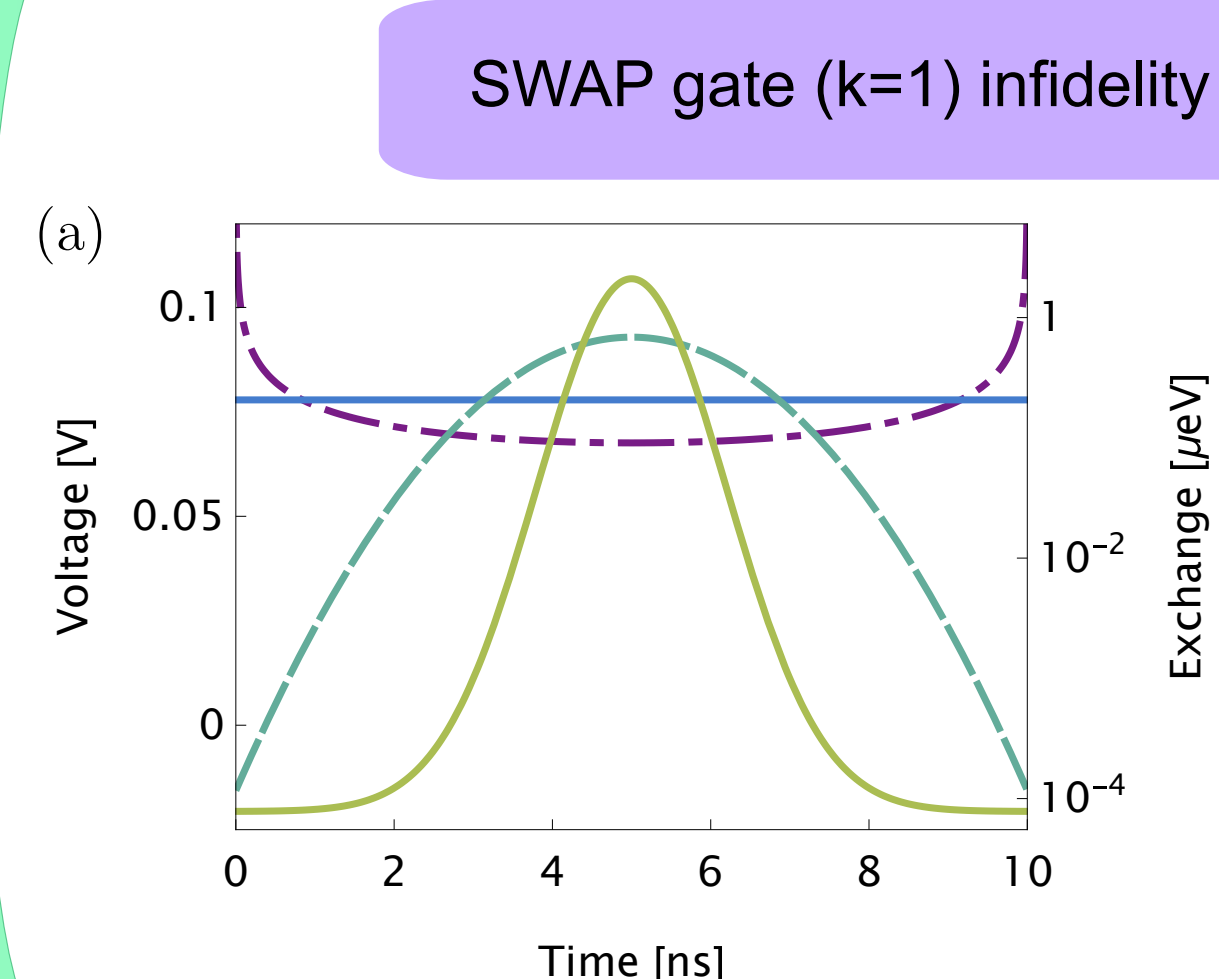
$$S_{\text{opt}}(\tau) = \delta(\tau - 0^+)$$

Results

Stationary noise

Optimal voltage pulse shape [Fig. (a)] is long, low-amplitude & broad:

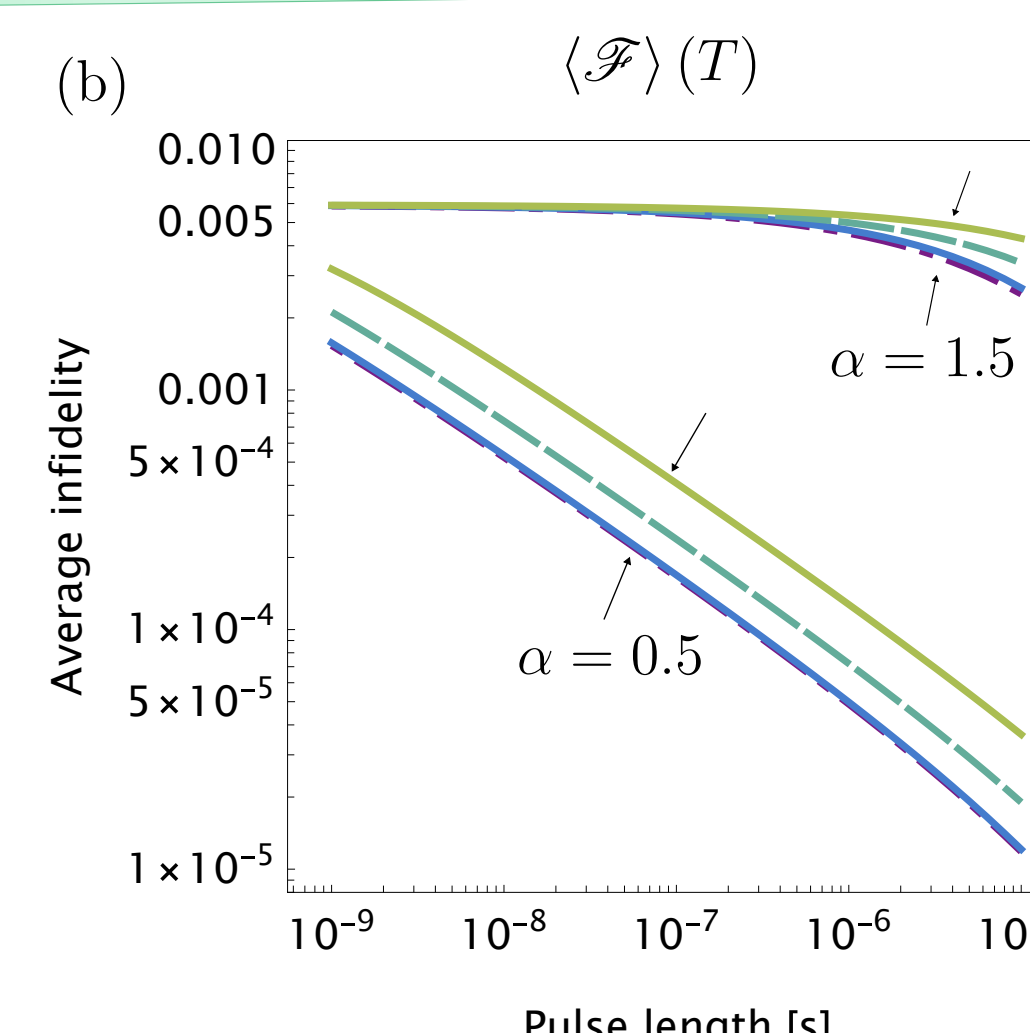
$$V_{\text{opt}}(t) = C(V_0, \alpha) - \frac{\alpha}{2\varkappa} \ln \left[\frac{t}{T} \left(1 - \frac{t}{T} \right) \right]$$



$\langle \mathcal{F} \rangle(T)$

Average infidelity decreases with pulse length [Fig. (b)] for all noise colors $\alpha \in (0, 2)$

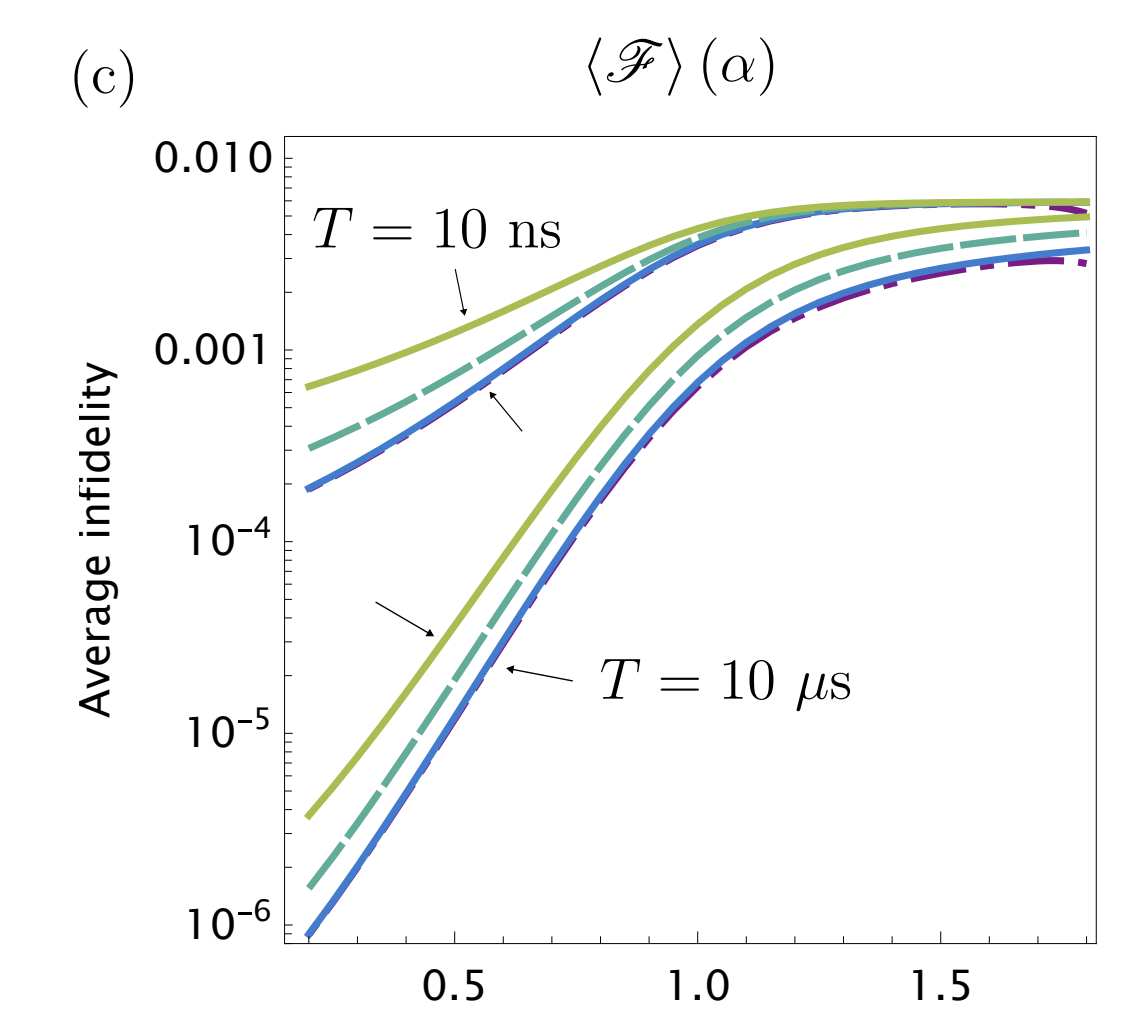
♦ Decrease is fastest in weakly-correlated noise environments (with small α values): -5.2 dB/dec for $\alpha = 0.5$



$\langle \mathcal{F} \rangle(\alpha)$

Noises with smaller α values [Fig. (c)] give: ✓ lower infidelity

✓ biggest advantage of using optimal shape: ~4x drop in infidelity vs. a Gaussian voltage pulse at $\alpha = 0.2$



Device-specific parameters [3]: $V_0 = 0.04$ V, $J(V_0) = 0.01$ μ eV, $\varkappa = 80$ V⁻¹

Nonstationary fBm

♦ Optimal pulse: as short & localized as possible

♦ Slow growth of infidelity with pulse length: $\langle \mathcal{F} \rangle \propto T^{\alpha-1}$

Discussion: experimental implications

- Strong exchange coupling regimes may not be necessary for high fidelity
- This might ease requirements on fabrication by simplifying device layouts
- With the presence of spin decoherence, we expect a **sweet spot** in pulse length T
- Our strategy is anticipated to become **increasingly more useful** as T₂ values rise thanks to materials and fabrication improvements

Acknowledgements

- ♦ Canada First Research Excellence Fund (Transformative Quantum Technologies)
- ♦ Natural Sciences and Engineering Research Council (NSERC) of Canada

References

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- [2] W. E. Williams, *A class of integral equations*, Mathematical Proceedings of the Cambridge Philosophical Society, Mathematical Proceedings of the Cambridge Philosophical Society 59, 589 (1963).
- [3] B. Buonacorsi, M. Korkusinski, B. Khromets, and J. Baugh, Optimizing lateral quantum dot geometries for reduced exchange noise, arXiv:2012.10512 (2020).